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- Member of the Texas Instruments Widebus™ Family
- Independent Asynchronous Inputs and Outputs
- Read and Write Operations Can Be Synchronized to Independent System Clocks
- Programmable Almost-Full/Almost-Empty Flag
- Pin-to-Pin Compatible With SN74ACT7881 and SN74ACT7811

- Input-Ready, Output-Ready, and Half-Full Flags
- Cascadable in Word Width and/or Word Depth (See Application Information)
- Fast Access Times of 11 ns With a 50-pF Load
- High Output Drive for Direct Bus Interface
- Package Options Include 68-Pin PLCC (FN) or Space-Saving 80-Pin Shrink Quad Flat (PN) Packages

FN PACKAGE (TOP VIEW)





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NC - No internal connection

#### description

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. The SN74ACT7882 is organized as 2048 bits deep  $\times$  18 bits wide. The SN74ACT7882 processes data at rates up to 67 MHz and access times of 11 ns in a bit-parallel format. Data outputs are noninverting with respect to the data inputs. Expansion is easily accomplished in both word width and word depth.

The SN74ACT7882 has normal input bus-to-output bus asynchronous operation. The special enable circuitry adds the ability to synchronize independent reads and writes to their respective system clocks.

The SN74ACT7882 is characterized for operation from 0°C to 70°C.



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996

#### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the 68-pin PLCC (FN) package.



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996

#### functional block diagram





SCAS445A - JUNE 1994 - REVISED DECEMBER 1996

#### **Terminal Functions<sup>†</sup>**

Т	TERMINAL I/O DESCRIPTION						
NAME	NO.	I/O	DESCRIPTION				
			Almost-full/almost-empty flag. The AF/AE boundary is defined by the almost-full/almost-empty offset value (X). This value can be programmed during reset or the default value of 256 can be used. AF/AE is high when the number of words in memory is less than or equal to X. AF/AE is also high when the number of words in memory is greater than or equal to ( $2048 - X$ ). Programming the almost-full/almost-empty offset value (X) is accomplished during a reset cycle. The almost-full/almost-empty offset value (X) is either user-defined or the default value of X = 256. The procedure to program AF/AE is as follows:				
			User-defined X				
AF/AE	33	0	Step 1: Take DAF from high to low. The high-to-low transition of DAF input stores the binary value on the data inputs as X. The following bits are used, listed from most significant bit to least significant bit D9–D0.				
			Step 2: If RESET is not already low, take RESET low.				
			Step 3: With DAF held low, take RESET high. This defines AF/AE using X.				
			NOTE: To retain the current (X) offset, keep DAF low during subsequent reset cycles. Default X				
			To redefine AF/AE using the default value of X = 256, hold $\overline{DAF}$ high during the reset cycle.				
DAF	27	I	Define almost-full. The high-to-low transition of DAF stores the binary value of data inputs as the almost-full/almost-empty offset value (X). With DAF held low, a RESET cycle defines the almost-full/almost-empty (AF/AE) flag using X.				
D0–D17	26–19, 17, 15–7	I	Data inputs for 18-bit-wide data to be stored in the memory. A high-to-low transition on $\overline{DAF}$ captures data for the almost-empty/almost-full offset (X) from D9–D0.				
HF	36	0	Half-full flag. HF is high when the FIFO contains 1024 or more words and is low when the number of words in memory is less than half the depth of the FIFO.				
IR	35	0	Input-ready flag. IR is high when the FIFO is not full and low when the device is full. During reset, IR is driven low on the rising edge of the second WRTCLK pulse. IR is then driven high on the rising edge of the second WRTCLK pulse after RESET goes high. After the FIFO is filled and IR is driven low, IR is driven high on the second WRTCLK pulse after the first valid read.				
OE	2	I	Output enable. The Q0–Q17 outputs are in the high-impedance state when OE is low. OE must be high before the rising edge of RDCLK to read a word from memory.				
OR	66	0	Output-ready flag. OR is high when the FIFO is not empty and low when it is empty. During reset, OR is set low on the rising edge of the third RDCLK pulse. OR is set high on the rising edge of the third RDCLK pulse to occur after the first word is written into the FIFO. OR is set low on the rising edge of the first RDCLK pulse after the last word is read.				
Q0–Q17	38–39, 41–42, 44, 46–47, 49–50, 52–53, 55–56, 58–59, 61, 63–64	0	Data out. The first data word to be loaded into the FIFO is moved to $Q0-Q17$ on the rising edge of the third RDCLK pulse to occur after the first valid write. RDEN1 and RDEN2 do not affect this operation. Following data is unloaded on the rising edge of RDCLK when RDEN1, RDEN2, OE, and OR are high.				
RDCLK	5	-	Read clock. Data is read out of memory on the low-to-high transition at RDCLK if OR, OE, and RDEN1 and RDEN2 are high. RDCLK is a free-running clock and functions as the synchronizing clock for all data transfers out of the FIFO. OR is also driven synchronously with respect to RDCLK.				
RDEN1, RDEN2	4 3	Ι	Read enable. RDEN1 and RDEN2 must be high before a rising edge on RDCLK to read a word out of memory. RDEN1 and RDEN2 are not used to read the first word stored in memory.				
RESET	1	I	Reset. A reset is accomplished by taking RESET low and generating a minimum of four RDCLK and WRTCLK cycles. This ensures that the internal read and write pointers are reset and that OR, HF, and IR are low, and AF/AE is high. The FIFO must be reset upon power up. With DAF at a low level, a low pulse on RESET defines AF/AE using the almost-full/almost-empty offset value (X), where X is the value previously stored. DAF held high during a RESET cycle will define the AF/AE flag using the default value of $X = 256$ .				

<sup>†</sup> Pin numbers shown are for the 68-pin PLCC (FN) package.



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996

#### Terminal Functions (Continued)<sup>†</sup>

TER	MINAL	1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
WRTCLK	29	I	Write clock. Data is written into memory on a low-to-high transition of WRTCLK if IR, WRTEN1, and WRTEN2 are high. WRTCLK is a free-running clock and functions as the synchronizing clock for all data transfers into the FIFO. IR is also driven synchronously with respect to WRTCLK.
WRTEN1, WRTEN2	30 31	I	Write enable. WRTEN1 and WRTEN2 must be high before a rising edge on WRTCLK for a word to be written into memory. WRTEN1 and WRTEN2 do not affect the storage of the almost-full/almost-empty offset value (X).

<sup>†</sup> Pin numbers shown are for the 68-pin PLCC (FN) package.



<sup>†</sup> X is the binary value on D9–D0.

Figure 1. Reset Cycle: Define AF/AE Using a Programmed Value of X



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996



Figure 2. Reset Cycle: Define AF/AE Using the Default Value



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996

RESET	
DAF	Don't Care
WRTCLK	── <u></u> ╋ <u></u>
WRTEN1	
WRTEN2	
D0D17	w1 w2 w3 w4 55 55 55 55 65 <
RDCLK	
RDEN1	
RDEN2	
OE	
Q0–Q17	Invalid W1
OR	
AF/AE	
HF	
IR	
	DATA WORD NUMBERS FOR FLAG TRANSITIONS

TRANSITION WORD							
Α	В	С					
W1025	W(2049 – X)	W20495					

Figure 3. Write



### SN74ACT7882 2048 imes 18 CLOCKED FIRST-IN, FIRST-OUT MEMORY

SCAS445A - JUNE 1994 - REVISED DECEMBER 1996



#### DATA WORD NUMBERS FOR FLAG TRANSITIONS

TRANSITION WORD									
A B		C D		Е	F				
W1025	W1030	W(2048 – X)	W(2049 – X)	W2048	W2049				

Figure 4. Read



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996

#### absolute maximum ratings over operating free-air temperature range<sup>†</sup>

Supply voltage range, V <sub>CC</sub>	
Input voltage, V <sub>I</sub>	
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range, T <sub>A</sub>	0°C to 70°C
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

		MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	V
VIH	High-level input voltage	2		V
VIL	Low-level input voltage		0.8	V
ЮН	High-level output current		-8	mA
IOL	Low-level output current		16	mA
Т <sub>А</sub>	Operating free-air temperature	0	70	°C

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	Т	EST CONDITIONS	MIN	TYP‡	MAX	UNIT
VOH	V <sub>CC</sub> = 4.5 V,	I <sub>OH</sub> = -8 mA	2.4			V
VOL	V <sub>CC</sub> = 4.5 V,	I <sub>OL</sub> = 16 mA			0.5	V
lj	V <sub>CC</sub> = 5.5 V,	$V_{I} = V_{CC} \text{ or } 0$			±5	μA
I <sub>OZ</sub>	V <sub>CC</sub> = 5.5 V,	$V_{O} = V_{CC} \text{ or } 0$			±5	μA
1 8	$V_{I} = V_{CC} - 0.2 V \text{ or } 0$				400	μA
I <sub>CC</sub> §	One input at 3.4 V,	Other inputs at $V_{CC}$ or GND			1	mA
C <sub>i</sub>	$V_{I} = 0,$	f = 1 MHz		4		pF
Co	$V_{O} = 0,$	f = 1 MHz		8		pF

<sup>‡</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

§ ICC tested with outputs open.



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996

### timing requirements over recommended ranges of supply voltage and operating free-air temperature (see Figures 1 through 4)

			'ACT78	382-15	'ACT78	82-20	'ACT78	82-30	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
fclock	Clock frequency		67		50		33.4		MHz
		WRTCLK high	5		7		8.5		
	WRTCLK low	6		7		11			
tw	Pulse duration	RDCLK high	5		7		8.5		ns
		RDCLK low	6		7		11		
		DAF high (default AF/AE value)	7		8		10		
		Data in (D0–D17) before WRTCLK <sup>↑</sup>	5		5		5		
	t <sub>SU</sub> Setup time	WRTEN1, WRTEN2 high before WRTCLK1	4		5		5		
		OE, RDEN1, RDEN2 high before RDCLK <sup>↑</sup>	4		5		5		ns
t <sub>su</sub>		Reset: RESET low before first WRTCLK↑ and RDCLK↑†	5		6		7		
t <sub>su</sub>		Define AF/AE: D0–D9 before $\overline{\text{DAF}}\downarrow$	5		5		5		
		Define AF/AE: DAF↓ before RESET↑	4		6		7		
		Define AF/AE (default): DAF high before RESET↑	4		5		5		
		Data in (D0–D17) after WRTCLK↑	0		0		0		
		WRTEN1, WRTEN2 high after WRTCLK↑	0		0		0		
		OE, RDEN1, RDEN2 high after RDCLK <sup>↑</sup>	0		0		1		
<sup>t</sup> h	Hold time	Reset: RESET low after fourth WRTCLK↑ and RDCLK↑†	0		0		0		ns
		Define AF/AE: D0–D9 after $\overline{\text{DAF}}\downarrow$	0		0		0		
<sup>t</sup> h		Define AF/AE: DAF low after RESET↑	0		0		0		
		Define AF/AE (default): DAF high after RESET↑	0		0		0		

<sup>†</sup> To permit the clock pulse to be utilized for reset purposes

### switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figures 7 and 8)

PARAMETER	FROM	ТО	'ACT78	382-15	'ACT78	382-20	'ACT78	382-30	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
f <sub>max</sub>	WRTCLK or RDCLK		67		50		33.4		MHz
<sup>t</sup> pd		Any Q	3	12	3	13	3	18	20
t <sub>pd</sub> ‡	RDCLK1	Ally Q							ns
<sup>t</sup> pd	WRTCLK↑	IR	2	8	2	9.5	2	12	00
<sup>t</sup> pd	RDCLK↑	OR	2	8	2	9.5	2	12	ns
<b>4</b> .	WRTCLK↑	AF/AE	6	17	6	19	6	22	ns
<sup>t</sup> pd	RDCLK↑	AF/AE	6	17	6	19	6	22	22
<sup>t</sup> PLH	WRTCLK↑	HF	6	14	6	17	6	21	
<sup>t</sup> PHL	RDCLK↑	ПГ	6	14	6	17	6	21	ns
<sup>t</sup> PLH	DEOET	AF/AE	3	12	3	17	3	21	
<sup>t</sup> PHL	RESET↓	HF	3	14	3	19	3	23	ns
t <sub>en</sub>		Δην Ο	2	9	2	11	2	11	200
<sup>t</sup> dis	OE	Any Q	2	10	2	14	2	14	ns

<sup>‡</sup> This parameter is measured with  $C_L = 30 \text{ pF}$  (see Figure 5).

SCAS445A - JUNE 1994 - REVISED DECEMBER 1996

#### operating characteristics, $V_{CC} = 5 V$ , $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS		
Cpd	Power dissipation capacitance per 1K bits	CL = 50 pF,	f = 5 MHz	65	pF



Figure 5



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996



#### calculating power dissipation

The maximum power dissipation (P<sub>T</sub>) of the SN74ACT7882 can be calculated using:

 $\mathsf{P}_{\mathsf{T}} = \mathsf{V}_{\mathsf{C}\mathsf{C}} \times [\mathsf{I}_{\mathsf{C}\mathsf{C}} + (\mathsf{N} \times \Delta \mathsf{I}_{\mathsf{C}\mathsf{C}} \times \mathsf{d}_{\mathsf{C}})] + \Sigma(\mathsf{C}_{\mathsf{pd}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_{\mathsf{i}}) + \Sigma(\mathsf{C}_{\mathsf{L}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_{\mathsf{o}})$ 

where:

- $I_{CC}$  = power-down  $I_{CC}$  maximum
- N = number of inputs driven by a TTL device

 $\Delta I_{CC}$  = increase in supply current

- dc = duty cycle of inputs at a TTL high level of 3.4 V
- C<sub>pd</sub> = power dissipation capacitance
- C<sub>L</sub> = output capacitive load
- f<sub>i</sub> = data input frequency
- fo = data output frequency



SCAS445A - JUNE 1994 - REVISED DECEMBER 1996







#### **APPLICATION INFORMATION**

#### expanding the SN74ACT7882

The SN74ACT7882 is expandable in both word width and word depth. Word-depth expansion is accomplished by connecting the devices in series such that data flows through each device in the chain. Figure 9 shows two SN74ACT7882 devices configured for depth expansion. The common clock between the devices can be tied to either the write clock (WRTCLK) of the first device or the read clock (RDCLK) of the last device. The output-ready flag (OR) of the previous device and the input-ready flag (IR) of the next device maintain data flow to the last device in the chain whenever space is available.

Figure 10 is an example of two SN74ACT7882 devices in word-width expansion. Width expansion is accomplished by simply connecting all common control signals between the devices and creating composite input-ready (IR) and output-ready (OR) signals. The almost-full/almost-empty flag (AF/AE) and half-full flag (HF) can be sampled from any one device. Depth expansion and width expansion can be used together.



Figure 9. Word-Depth Expansion: 4096 Words × 18 Bits



Figure 10. Word-Width Expansion: 2048 Words × 36 Bits



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